

### **BD241/A/B/C**

# **Medium Power Linear and Switching Applications**

Complement to BD242/A/B/C respectively



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BD241	45	V
	: BD241A	60	V
	: BD241B	80	V
	: BD241C	100	V
V <sub>CER</sub>	Collector-Emitter Voltage		
	: BD241	55	V
	: BD241A	70	V
	: BD241B	90	V
	: BD241C	115	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	3	Α
I <sub>CP</sub>	*Collector Current (Pulse)	5	Α
I <sub>B</sub>	Base Current	1	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

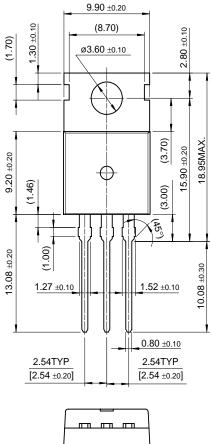
### **Electrical Characteristics** $T_C=25^{\circ}C$ unless otherwise noted

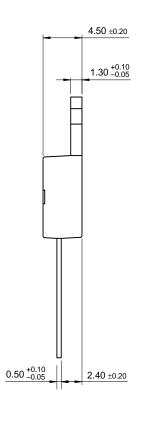
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CFO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
	: BD241	$I_C = -30 \text{mA}, I_B = 0$	45			V
	: BD241A		60			V
	: BD241B		80			V
	: BD241C		100			V
I <sub>CEO</sub>	Collector Cut-off Current : BD241/A	$V_{CE} = 30V, I_{B} = 0$			0.3	mA
	: BD241B/C	$V_{CE} = 60 \text{ V}, I_{B} = 0$			0.3	mA
I <sub>CES</sub>	Collector Cut-off Current : BD241	$V_{CE} = 45V, V_{BE} = 0$			0.2	mA
	: BD241A	$V_{CE} = 60V, V_{BE} = 0$			0.2	mA
	: BD241B	$V_{CE} = 80V, V_{BE} = 0$			0.2	mA
	: BD241C	$V_{CE} = 100V, V_{BE} = 0$			0.2	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 4V, I_{C} = 1A$	25			
		$V_{CE} = 4V, I_{C} = 3A$	10			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 0.6A$			1.2	V
V <sub>RF</sub> (on)	* Base-Emitter ON Voltage	$V_{CE} = 4V, I_{C} = 3A$			1.8	V

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# **Package Demensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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